ROHM SEMICONDUCTOR

Technical Note

Hall ICs

# Omnipolar Detection Hall ICs

Pb Free ROHM Electronic Components

RoHS Directive Compliance

## BU52001GUL,BU52011HFV,BU52021HFV,BU52015GUL,BU52025G,BU52053NVX, BU52054GWZ,BU52055GWZ,BU52056NVX,BU52061NVX,BD7411G

No.10045EGT02

### ●Description

The omnipolar Hall ICs are magnetic switches that can operate both S-and N-pole, upon which the output goes from Hi to Low. In addition to regular single-output Hall ICs, We offer a lineup of dual-output units with a reverse output terminal (active High).

### ●Features

1) Omnipolar detection
2) Micro power operation (small current using intermittent operation method)(BD7411G is excluded.)
3) Ultra-compact and thin wafer level CSP4 package (BU52054GWZ, BU52055GWZ)
4) Ultra-compact wafer level CSP4 package (BU52015GUL, BU52001GUL)
5) Ultra-Small outline package SSON004X1216 (BU52061NVX, BU52053NVX, BU52056NVX)
6) Ultra-Small outline package HVSOF5 (BU52011HFV, BU52021HFV)
7) Small outline package (BU52025G, BD7411G)
8) Line up of supply voltage
   For 1.8V Power supply voltage (BU52054GWZ, BU52055GWZ, BU52015GUL, BU52061NVX, BU52053NVX, BU52056NVX, BU52011HFV)
   For 3.0V Power supply voltage (BU52001GUL)
   For 3.3V Power supply voltage (BU52021HFV, BU52025G)
   For 5.0V Power supply voltage (BD7411G)
9) Dual output type (BU52015GUL)
10) High ESD resistance 8kV (HBM) (6kV for BU52056NVX)

### ●Applications

Mobile phones, notebook computers, digital video camera, digital still camera, white goods etc.

### ●Lineup matrix

| Product name | Supply voltage (V) | Operate point (mT) | Hysteresis (mT) | Period (ms) | Supply current (AVG) (A) | Output type | Package |
|---|---|---|---|---|---|---|---|
| BU52054GWZ | 1.65～3.60 | +/-6.3 ※ | 0.9 | 50 | 5.0μ | CMOS | UCSP35L1 |
| BU52055GWZ | 1.65～3.60 | +/-4.1 ※ | 0.8 | 50 | 5.0μ | CMOS | UCSP35L1 |
| BU52015GUL | 1.65～3.30 | +/-3.0 ※ | 0.9 | 50 | 5.0μ | CMOS | VCSP50L1 |
| BU52001GUL | 2.40～3.30 | +/-3.7 ※ | 0.8 | 50 | 8.0μ | CMOS | VCSP50L1 |
| BU52061NVX | 1.65～3.60 | +/-3.3 ※ | 0.9 | 50 | 4.0μ | CMOS | SSON004X1216 |
| BU52053NVX | 1.65～3.60 | +/-3.0 ※ | 0.9 | 50 | 5.0μ | CMOS | SSON004X1216 |
| BU52056NVX | 1.65～3.60 | +/-4.6 ※ | 0.8 | 50 | 5.0μ | CMOS | SSON004X1216 |
| BU52011HFV | 1.65～3.30 | +/-3.0 ※ | 0.9 | 50 | 5.0μ | CMOS | HVSOF5 |
| BU52021HFV | 2.40～3.60 | +/-3.7 ※ | 0.8 | 50 | 8.0μ | CMOS | HVSOF5 |
| BU52025G | 2.40～3.60 | +/-3.7 ※ | 0.8 | 50 | 8.0μ | CMOS | SSOP5 |
| BD7411G | 4.50～5.50 | +/-3.4 ※ | 0.4 | - | 2.0m | CMOS | SSOP5 |

※Plus is expressed on the S-pole; minus on the N-pole


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## ●Absolute maximum ratings

BU52054GWZ, BU52055GWZ (Ta=25℃)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Power Supply Voltage | $V_{DD}$ | -0.1～+4.5※1 | V |
| Output Current | $I_{OUT}$ | ±0.5 | mA |
| Power Dissipation | Pd | 100※2 | mW |
| Operating Temperature Range | $T_{opr}$ | -40～+85 | ℃ |
| Storage Temperature Range | $T_{stg}$ | -40～+125 | ℃ |

※1. Not to exceed Pd
※2. Reduced by 1.00mW for each increase in Ta of 1℃ over 25℃ (mounted on 24mm × 20mm Glass-epoxy PCB)

BU52015GUL (Ta=25℃)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Power Supply Voltage | $V_{DD}$ | -0.1～+4.5※3 | V |
| Output Current | $I_{OUT}$ | ±0.5 | mA |
| Power Dissipation | Pd | 420※4 | mW |
| Operating Temperature Range | $T_{opr}$ | -40～+85 | ℃ |
| Storage Temperature Range | $T_{stg}$ | -40～+125 | ℃ |

※3. Not to exceed Pd
※4. Reduced by 4.20mW for each increase in Ta of 1℃ over 25℃ (mounted on 50mm × 58mm Glass-epoxy PCB)

BU52001GUL (Ta=25℃)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Power Supply Voltage | $V_{DD}$ | -0.1～+4.5※5 | V |
| Output Current | $I_{OUT}$ | ±1 | mA |
| Power Dissipation | Pd | 420※6 | mW |
| Operating Temperature Range | $T_{opr}$ | -40～+85 | ℃ |
| Storage Temperature Range | $T_{stg}$ | -40～+125 | ℃ |

※5. Not to exceed Pd
※6. Reduced by 4.20mW for each increase in Ta of 1℃ over 25℃ (mounted on 50mm × 58mm Glass-epoxy PCB)

BU52061NVX, BU52053NVX, BU52056NVX(Ta=25℃)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Power Supply Voltage | $V_{DD}$ | -0.1～+4.5※7 | V |
| Output Current | $I_{OUT}$ | ±0.5 | mA |
| Power Dissipation | Pd | 2049※8 | mW |
| Operating Temperature Range | $T_{opr}$ | -40～+85 | ℃ |
| Storage Temperature Range | $T_{stg}$ | -40～+125 | ℃ |

※7. Not to exceed Pd
※8. Reduced by 4.20mW for each increase in Ta of 1℃ over 25℃ (mounted on 50mm × 58mm Glass-epoxy PCB)

BU52011HFV (Ta=25℃)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Power Supply Voltage | $V_{DD}$ | -0.1～+4.5※9 | V |
| Output Current | $I_{OUT}$ | ±0.5 | mA |
| Power Dissipation | Pd | 536※10 | mW |
| Operating Temperature Range | $T_{opr}$ | -40～+85 | ℃ |
| Storage Temperature Range | $T_{stg}$ | -40～+125 | ℃ |

※9. Not to exceed Pd
※10. Reduced by5.36mW for each increase in Ta of 1℃ over 25℃ (mounted on 70mm × 70 mm × 1.6mm Glass-epoxy PCB)

BU52021HFV (Ta=25℃)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Power Supply Voltage | $V_{DD}$ | -0.1～+4.5※11 | V |
| Output Current | $I_{OUT}$ | ±1 | mA |
| Power Dissipation | Pd | 536※12 | mW |
| Operating Temperature Range | $T_{opr}$ | -40～+85 | ℃ |
| Storage Temperature Range | $T_{stg}$ | -40～+125 | ℃ |

※11 Not to exceed Pd
※12. Reduced by 5.36mW for each increase in Ta of 1℃ over 25℃ (mounted on 70mm × 70 mm × 1.6mm Glass-epoxy PCB)

BU52025G (Ta=25℃)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Power Supply Voltage | $V_{DD}$ | -0.1～+4.5※13 | V |
| Output Current | $I_{OUT}$ | ±1 | mA |
| Power Dissipation | Pd | 540※14 | mW |
| Operating Temperature Range | $T_{opr}$ | -40～+85 | ℃ |
| Storage Temperature Range | $T_{stg}$ | -40～+125 | ℃ |

※13. Not to exceed Pd
※14. Reduced by 5.40mW for each increase in Ta of 1℃ over 25℃ (mounted on 70mm × 70 mm × 1.6mm Glass-epoxy PCB)

BD7411G (Ta=25℃)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Power Supply Voltage | $V_{DD}$ | -0.3～+7.0※15 | V |
| Output Current | $I_{OUT}$ | ±1 | mA |
| Power Dissipation | Pd | 540※16 | mW |
| Operating Temperature Range | $T_{opr}$ | -40～+85 | ℃ |
| Storage Temperature Range | $T_{stg}$ | -55～+150 | ℃ |

※15. Not to exceed Pd
※16. Reduced by 5.40mW for each increase in Ta of 1℃ over 25℃ (mounted on 70mm × 70 mm × 1.6mm Glass-epoxy PCB)


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## ●Magnetic, Electrical characteristics

BU52054GWZ (Unless otherwise specified, $V_{DD}$=1.80V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 1.65 | 1.80 | 3.60 | V | |
| Operate Point | $B_{opS}$ | - | 6.3 | 7.9 | mT | |
| | $B_{opN}$ | -7.9 | -6.3 | - | | |
| Release Point | $B_{rpS}$ | 3.5 | 5.4 | - | mT | |
| | $B_{rpN}$ | - | -5.4 | -3.5 | | |
| Hysteresis | $B_{hysS}$ | - | 0.9 | - | mT | |
| | $B_{hysN}$ | - | 0.9 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.2 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※17<br>$I_{OUT}$ =-0.5mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.2 | V | $B<B_{opN}$, $B_{opS}<B$ ※17<br>$I_{OUT}$ =+0.5mA |
| Supply Current | $I_{DD(AVG)}$ | - | 5 | 8 | μA | Average |
| Supply Current During Startup Time | $I_{DD(EN)}$ | - | 2.8 | - | mA | During Startup Time Value |
| Supply Current During Standby Time | $I_{DD(DIS)}$ | - | 1.8 | - | μA | During Standby Time Value |

※17 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BU52055GWZ (Unless otherwise specified, $V_{DD}$=1.80V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 1.65 | 1.80 | 3.60 | V | |
| Operate Point | $B_{opS}$ | - | 4.1 | 5.5 | mT | |
| | $B_{opN}$ | -5.5 | -4.1 | - | | |
| Release Point | $B_{rpS}$ | 1.5 | 3.3 | - | mT | |
| | $B_{rpN}$ | - | -3.3 | -1.5 | | |
| Hysteresis | $B_{hysS}$ | - | 0.8 | - | mT | |
| | $B_{hysN}$ | - | 0.8 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.2 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※18<br>$I_{OUT}$ =-0.5mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.2 | V | $B<B_{opN}$, $B_{opS}<B$ ※18<br>$I_{OUT}$ =+0.5mA |
| Supply Current | $I_{DD(AVG)}$ | - | 5 | 8 | μA | Average |
| Supply Current During Startup Time | $I_{DD(EN)}$ | - | 2.8 | - | mA | During Startup Time Value |
| Supply Current During Standby Time | $I_{DD(DIS)}$ | - | 1.8 | - | μA | During Standby Time Value |

※18 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BU52015GUL (Unless otherwise specified, $V_{DD}$=1.80V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 1.65 | 1.80 | 3.30 | V | |
| Operate Point | $B_{opS}$ | - | 3.0 | 5.0 | mT | |
| | $B_{opN}$ | -5.0 | -3.0 | - | | |
| Release Point | $B_{rpS}$ | 0.6 | 2.1 | - | mT | |
| | $B_{rpN}$ | - | -2.1 | -0.6 | | |
| Hysteresis | $B_{hysS}$ | - | 0.9 | - | mT | |
| | $B_{hysN}$ | - | 0.9 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.2 | - | - | V | OUT1: $B_{rpN}<B<B_{rpS}$ ※19<br>OUT2: $B<B_{opN}$, $B_{opS}<B$<br>$I_{OUT}$ = -0.5mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.2 | V | OUT1: $B<B_{opN}$, $B_{opS}<B$ ※19<br>OUT2: $B_{rpN}<B<B_{rpS}$<br>$I_{OUT}$ = +0.5mA |
| Supply Current 1 | $I_{DD1(AVG)}$ | - | 5 | 8 | μA | $V_{DD}$=1.8V, Average |
| Supply Current During Startup Time 1 | $I_{DD1(EN)}$ | - | 2.8 | - | mA | $V_{DD}$=1.8V,<br>During Startup Time Value |
| Supply Current During Standby Time 1 | $I_{DD1(DIS)}$ | - | 1.8 | - | μA | $V_{DD}$=1.8V,<br>During Standby Time Value |
| Supply Current 2 | $I_{DD2(AVG)}$ | - | 8 | 12 | μA | $V_{DD}$=2.7V, Average |
| Supply Current During Startup Time 2 | $I_{DD2(EN)}$ | - | 4.5 | - | mA | $V_{DD}$=2.7V,<br>During Startup Time Value |
| Supply Current During Standby Time 2 | $I_{DD2(DIS)}$ | - | 4.0 | - | μA | $V_{DD}$=2.7V,<br>During Standby Time Value |

※19 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BU52001GUL (Unless otherwise specified, $V_{DD}$=3.0V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 2.4 | 3.0 | 3.3 | V | |
| Operate Point | $B_{opS}$ | - | 3.7 | 5.5 | mT | |
| | $B_{opN}$ | -5.5 | -3.7 | - | | |
| Release Point | $B_{rpS}$ | 0.8 | 2.9 | - | mT | |
| | $B_{rpN}$ | - | -2.9 | -0.8 | | |
| Hysteresis | $B_{hysS}$ | - | 0.8 | - | mT | |
| | $B_{hysN}$ | - | 0.8 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.4 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※20<br>$I_{OUT}$ =-1.0mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.4 | V | $B<B_{opN}, B_{opS}<B$ ※20<br>$I_{OUT}$ =+1.0mA |
| Supply Current | $I_{DD(AVG)}$ | - | 8 | 12 | μA | Average |
| Supply Current During Startup Time | $I_{DD(EN)}$ | - | 4.7 | - | mA | During Startup Time Value |
| Supply Current During Standby Time | $I_{DD(DIS)}$ | - | 3.8 | - | μA | During Standby Time Value |

※20 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BU52061NVX (Unless otherwise specified, $V_{DD}$=1.80V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 1.65 | 1.80 | 3.60 | V | |
| Operate Point | $B_{opS}$ | 2.3 | 3.3 | 4.7 | mT | |
| | $B_{opN}$ | -4.7 | -3.3 | -2.3 | | |
| Release Point | $B_{rpS}$ | 1.2 | 2.4 | 3.4 | mT | |
| | $B_{rpN}$ | -3.4 | -2.4 | -1.2 | | |
| Hysteresis | $B_{hysS}$ | - | 0.9 | - | mT | |
| | $B_{hysN}$ | - | 0.9 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.2 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※21<br>$I_{OUT}$ =-0.5mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.2 | V | $B<B_{opN}$, $B_{opS}<B$ ※21<br>$I_{OUT}$ =+0.5mA |
| Supply Current 1 | $I_{DD1(AVG)}$ | - | 4 | 7 | μA | VDD=1.8V, Average |
| Supply Current During Startup Time 1 | $I_{DD1(EN)}$ | - | 5.0 | - | mA | $V_{DD}$=1.8V,<br>During Startup Time Value |
| Supply Current During Standby Time 1 | $I_{DD1(DIS)}$ | - | 1.8 | - | μA | $V_{DD}$=1.8V,<br>During Standby Time Value |
| Supply Current 2 | $I_{DD2(AVG)}$ | - | 9 | 16 | μA | $V_{DD}$=3.0V, Average |
| Supply Current During Startup Time 2 | $I_{DD2(EN)}$ | - | 9.0 | - | mA | $V_{DD}$=3.0V,<br>During Startup Time Value |
| Supply Current During Standby Time 2 | $I_{DD2(DIS)}$ | - | 4.4 | - | μA | $V_{DD}$=3.0V,<br>During Standby Time Value |

※21 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BU52053NVX (Unless otherwise specified, $V_{DD}$=1.80V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 1.65 | 1.80 | 3.60 | V | |
| Operate Point | $B_{opS}$ | - | 3.0 | 5.0 | mT | |
| | $B_{opN}$ | -5.0 | -3.0 | - | | |
| Release Point | $B_{rpS}$ | 0.6 | 2.1 | - | mT | |
| | $B_{rpN}$ | - | -2.1 | -0.6 | | |
| Hysteresis | $B_{hysS}$ | - | 0.9 | - | mT | |
| | $B_{hysN}$ | - | 0.9 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.2 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※22<br>$I_{OUT}$ =-0.5mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.2 | V | $B<B_{opN}$, $B_{opS}<B$ ※22<br>$I_{OUT}$ =+0.5mA |
| Supply Current | $I_{DD(AVG)}$ | - | 5 | 8 | μA | Average |
| Supply Current During Startup Time | $I_{DD(EN)}$ | - | 2.8 | - | mA | During Startup Time Value |
| Supply Current During Standby Time | $I_{DD(DIS)}$ | - | 1.8 | - | μA | During Standby Time Value |

※22 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BU52011HFV (Unless otherwise specified, $V_{DD}$=1.80V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 1.65 | 1.80 | 3.30 | V | |
| Operate Point | $B_{opS}$ | - | 3.0 | 5.0 | mT | |
| | $B_{opN}$ | -5.0 | -3.0 | - | | |
| Release Point | $B_{rpS}$ | 0.6 | 2.1 | - | mT | |
| | $B_{rpN}$ | - | -2.1 | -0.6 | | |
| Hysteresis | $B_{hysS}$ | - | 0.9 | - | mT | |
| | $B_{hysN}$ | - | 0.9 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.2 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※23<br>$I_{OUT}$ =-0.5mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.2 | V | $B<B_{opN}$, $B_{opS}<B$ ※23<br>$I_{OUT}$ =+0.5mA |
| Supply Current 1 | $I_{DD1(AVG)}$ | - | 5 | 8 | μA | $V_{DD}$=1.8V, Average |
| Supply Current During Startup Time 1 | $I_{DD1(EN)}$ | - | 2.8 | - | mA | $V_{DD}$=1.8V,<br>During Startup Time Value |
| Supply Current During Standby Time 1 | $I_{DD1(DIS)}$ | - | 1.8 | - | μA | $V_{DD}$=1.8V,<br>During Standby Time Value |
| Supply Current 2 | $I_{DD2(AVG)}$ | - | 8 | 12 | μA | $V_{DD}$=2.7V, Average |
| Supply Current During Startup Time 2 | $I_{DD2(EN)}$ | - | 4.5 | - | mA | $V_{DD}$=2.7V,<br>During Startup Time Value |
| Supply Current During Standby Time 2 | $I_{DD2(DIS)}$ | - | 4.0 | - | μA | $V_{DD}$=2.7V,<br>During Standby Time Value |

※23 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BU52056NVX (Unless otherwise specified, $V_{DD}$=1.80V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 1.65 | 1.80 | 3.60 | V | |
| Operate Point | $B_{opS}$ | - | 4.6 | 6.4 | mT | |
| | $B_{opN}$ | -6.4 | -4.6 | - | | |
| Release Point | $B_{rpS}$ | 2.0 | 3.8 | - | mT | |
| | $B_{rpN}$ | - | -3.8 | -2.0 | | |
| Hysteresis | $B_{hysS}$ | - | 0.8 | - | mT | |
| | $B_{hysN}$ | - | 0.8 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.2 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※24<br>$I_{OUT}$ =-0.5mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.2 | V | $B<B_{opN}$, $B_{opS}<B$ ※24<br>$I_{OUT}$ =+0.5mA |
| Supply Current | $I_{DD(AVG)}$ | - | 5 | 8 | μA | Average |
| Supply Current During Startup Time | $I_{DD(EN)}$ | - | 2.8 | - | mA | During Startup Time Value |
| Supply Current During Standby Time | $I_{DD(DIS)}$ | - | 1.8 | - | μA | During Standby Time Value |

※24 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BU52021HFV,BU52025G (Unless otherwise specified, $V_{DD}$=3.0V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 2.4 | 3.0 | 3.6 | V | |
| Operate Point | $B_{opS}$ | - | 3.7 | 5.5 | mT | |
| | $B_{opN}$ | -5.5 | -3.7 | - | | |
| Release Point | $B_{rpS}$ | 0.8 | 2.9 | - | mT | |
| | $B_{rpN}$ | - | -2.9 | -0.8 | | |
| Hysteresis | $B_{hysS}$ | - | 0.8 | - | mT | |
| | $B_{hysN}$ | - | 0.8 | - | | |
| Period | $T_p$ | - | 50 | 100 | ms | |
| Output High Voltage | $V_{OH}$ | $V_{DD}$-0.4 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※25<br>$I_{OUT}$ =-1.0mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.4 | V | $B<B_{opN}$, $B_{opS}<B$ ※25<br>$I_{OUT}$ =+1.0mA |
| Supply Current | $I_{DD(AVG)}$ | - | 8 | 12 | μA | Average |
| Supply Current During Startup Time | $I_{DD(EN)}$ | - | 4.7 | - | mA | During Startup Time Value |
| Supply Current During Standby Time | $I_{DD(DIS)}$ | - | 3.8 | - | μA | During Standby Time Value |

※25 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period ($T_P$) to become definite output.
Radiation hardiness is not designed.


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BD7411G (Unless otherwise specified, $V_{DD}$=5.0V, Ta=25℃)

| Parameter | Symbol | Limits | | | Unit | Conditions |
|---|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | | |
| Power Supply Voltage | $V_{DD}$ | 4.5 | 5.0 | 5.5 | V | |
| Operate Point | $B_{opS}$ | - | 3.4 | 5.6 | mT | |
| | $B_{opN}$ | -5.6 | -3.4 | - | | |
| Release Point | $B_{rpS}$ | 1.5 | 3.0 | - | mT | |
| | $B_{rpN}$ | - | -3.0 | -1.5 | | |
| Hysteresis | $B_{hysS}$ | - | 0.4 | - | mT | |
| | $B_{hysN}$ | - | 0.4 | - | | |
| Output High Voltage | $V_{OH}$ | 4.6 | - | - | V | $B_{rpN}<B<B_{rpS}$ ※26<br>$I_{OUT}$ =-1.0mA |
| Output Low Voltage | $V_{OL}$ | - | - | 0.4 | V | $B<B_{opN}$, $B_{opS}<B$ ※26<br>$I_{OUT}$ =+1.0mA |
| Supply Current | $I_{DD}$ | - | 2 | 4 | mA | |

※26 B = Magnetic flux density
1mT=10Gauss
Positive (“+”) polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
Radiation hardiness is not designed.


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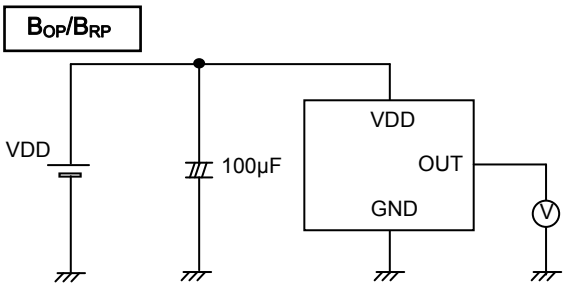
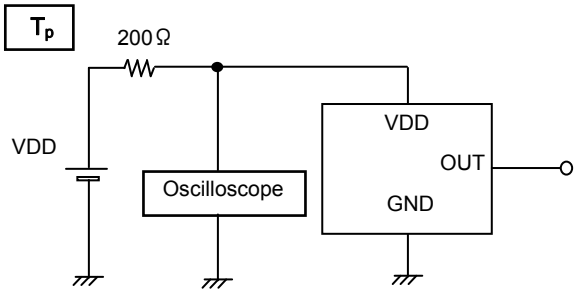
●Figure of measurement circuit



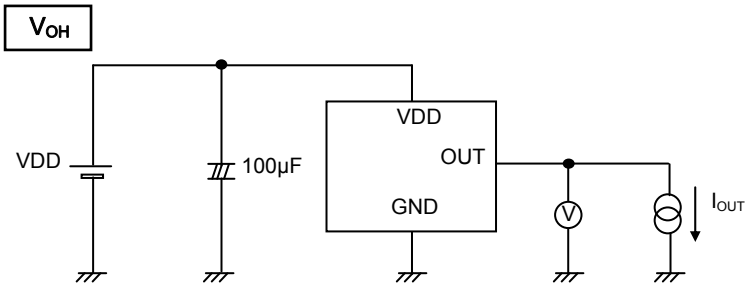

Bop and Brp are measured with applying the magnetic field from the outside.

Fig.1 $B_{op}$,$B_{rp}$ mesurement circuit



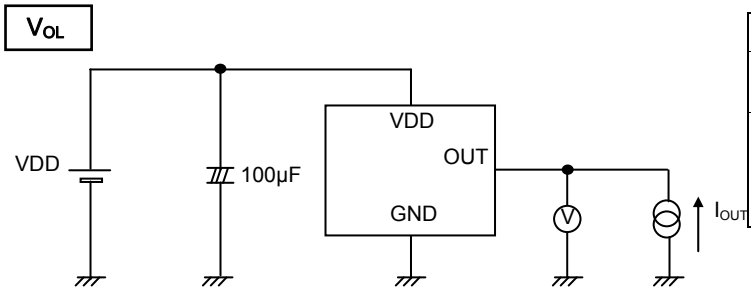

The period is monitored by Oscilloscope.

Fig.2 $T_p$ mesurement circuit



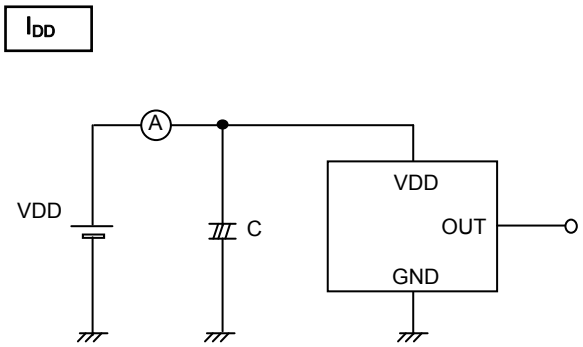

| Product Name | $I_{OUT}$ |
|---|---|
| BU52001GUL, BU52021HFV, BU52025G, BD7411G | 1.0mA |
| BU52054GWZ, BU52055GWZ, BU52015GUL, BU52061NVX, BU52053NVX, BU52056NVX, BU52011HFV | 0.5mA |

Fig.3 $V_{OH}$ mesurement circuit




| Product Name | $I_{OUT}$ |
|---|---|
| BU52001GUL, BU52021HFV, BU52025G, BD7411G | 1.0mA |
| BU52054GWZ, BU52055GWZ, BU52015GUL, BU52061NVX, BU52053NVX, BU52056NVX, BU52011HFV | 0.5mA |

Fig.4 $V_{OL}$ measurement circuit




| Product Name | C |
|---|---|
| BU52054GWZ, BU52055GWZ, BU52015GUL, BU52001GUL, BU52061NVX, BU52053NVX, BU52056NVX, BU52011HFV, BU52021HFV, BU52025G | 2200μF |
| BD7411G | 100μF |

Fig.5 $I_{DD}$ measurement circuit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## ●Technical (Reference) Data

### BU52054GWZ($V_{DD}$=1.65～3.6V type)

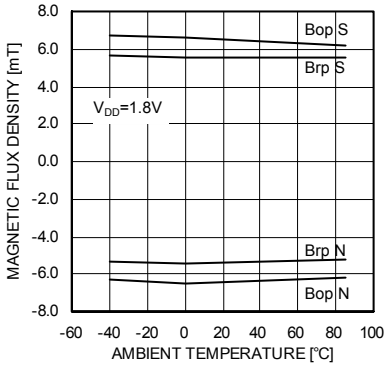


Fig.6 Bop,Brp– Ambient temperature

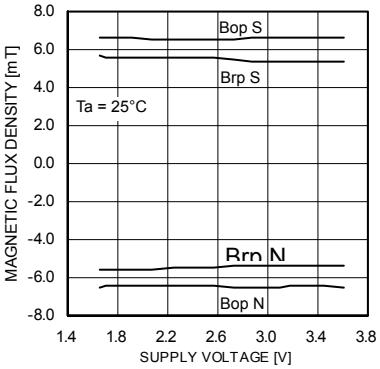


Fig.7 Bop,Brp– Supply voltage

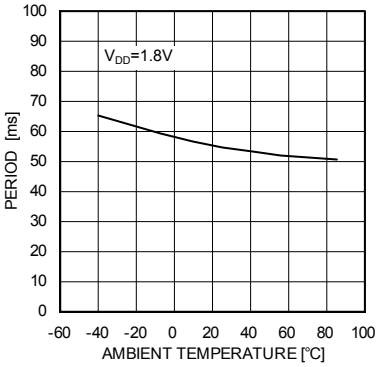


Fig.8 $T_P$– Ambient temperature

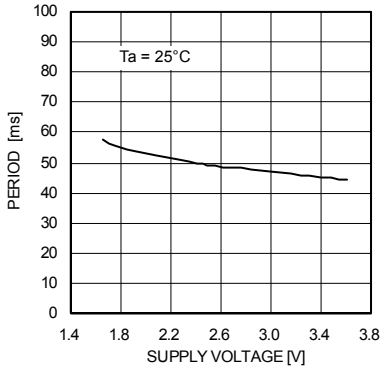


Fig.9 $T_P$– Supply voltage

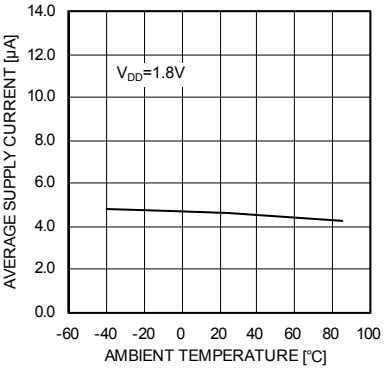


Fig.10 $I_{DD}$– Ambient temperature

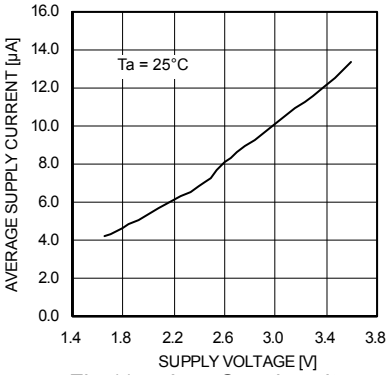


Fig.11 $I_{DD}$– Supply voltage

### BU52055GWZ($V_{DD}$=1.65～3.6V type)

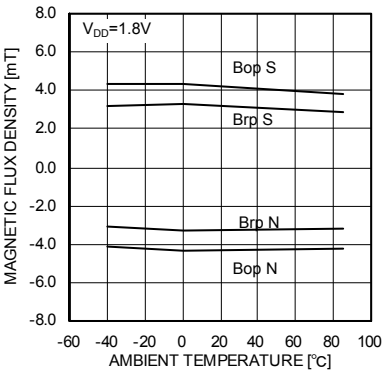


Fig.12 Bop,Brp– Ambient temperature

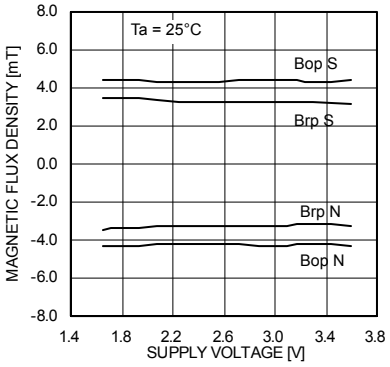


Fig.13 Bop,Brp– Supply voltage

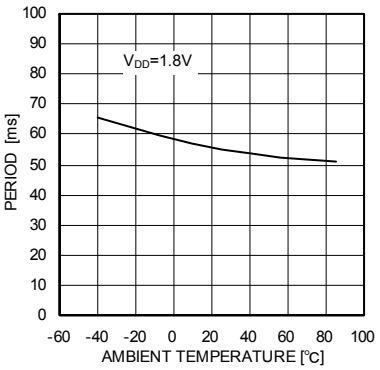


Fig.14 $T_P$ – Ambient temperature

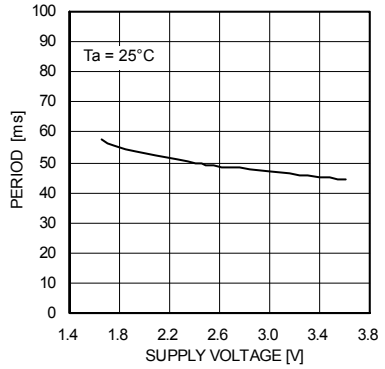


Fig.15 $T_P$– Supply voltage

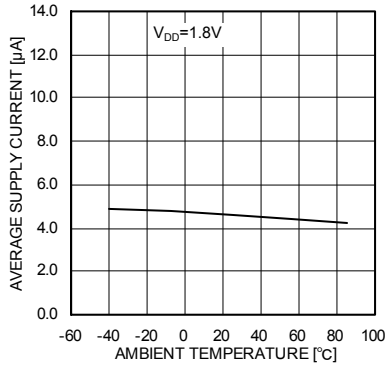


Fig.16 $I_{DD}$– Ambient temperature

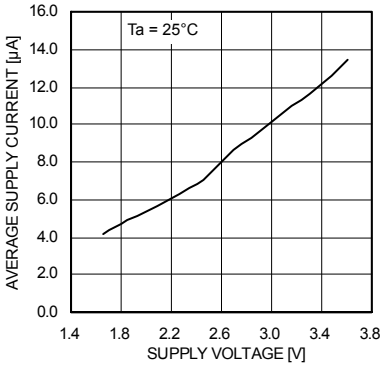


Fig.17 $I_{DD}$– Supply voltage


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## BU52015GUL, BU52011HFV ($V_{DD}$=1.65～3.3V type)

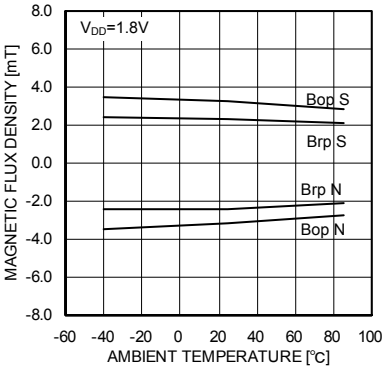


Fig.18 Bop,Brp– Ambient temperature

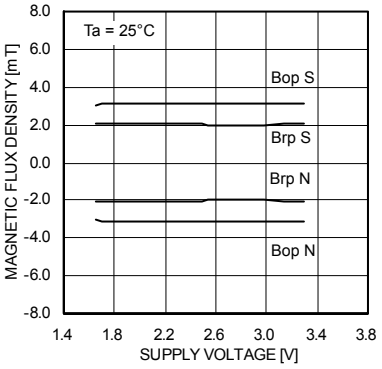


Fig.19 Bop,Brp Supply voltage

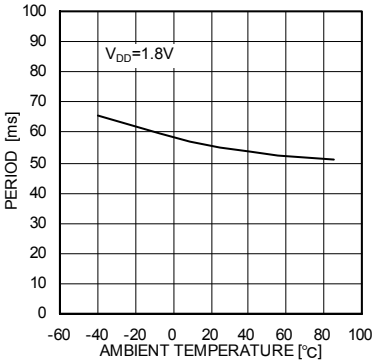


Fig.20 $T_P$ – Ambient temperature

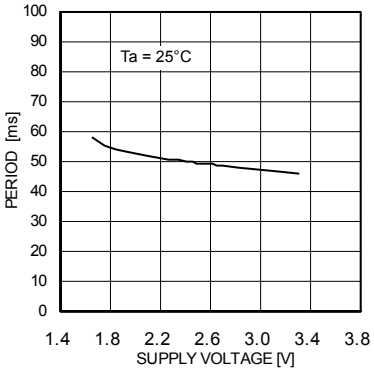


Fig.21 $T_P$– Supply voltage

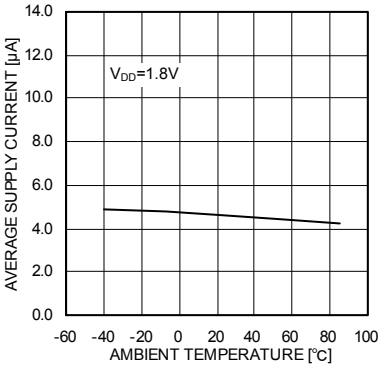


Fig.22 $I_{DD}$– Ambient temperature

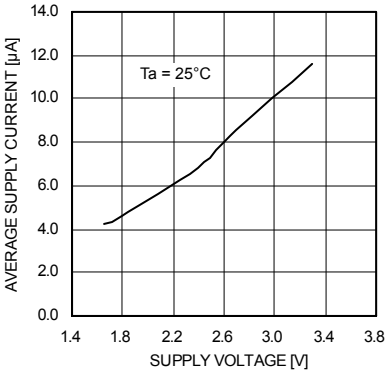


Fig.23 $I_{DD}$ – Supply voltage

## BU52001GUL ($V_{DD}$=2.4～3.3V type)

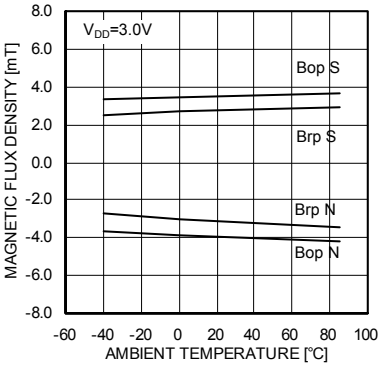


Fig.24 Bop,Brp–Ambient temperature

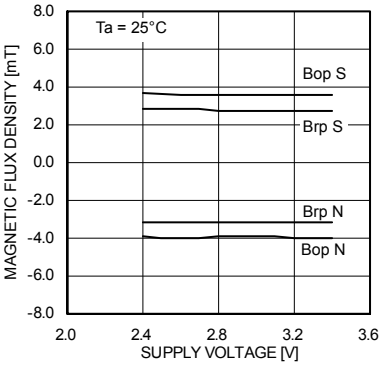


Fig.25 Bop,Brp– Supply voltage

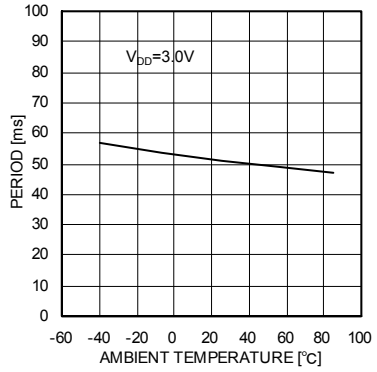


Fig.26 $T_P$– Ambient temperature

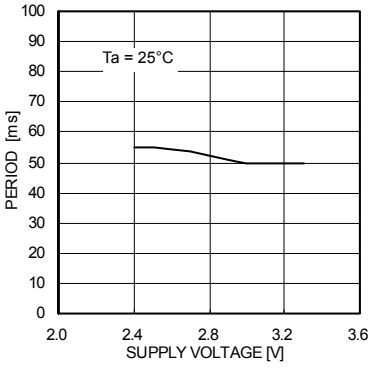


Fig.27 $T_P$– Supply voltage

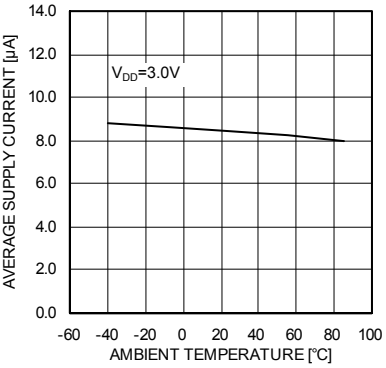


Fig.28 $I_{DD}$– Ambient temperature

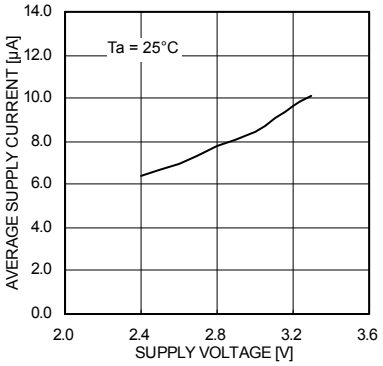


Fig.29 $I_{DD}$ – Supply voltage


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## BU52061NVX($V_{DD}$=1.65～3.6V type)

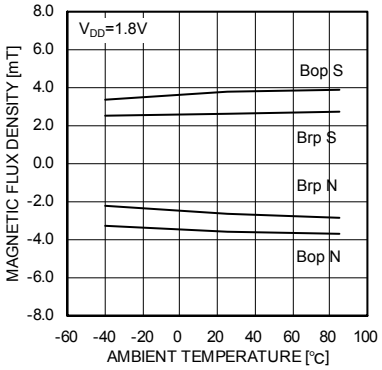


Fig.30 Bop,Brp– Ambient temperature

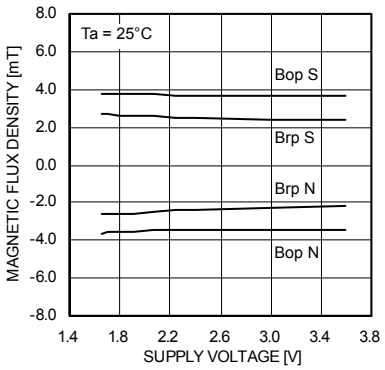


Fig.31 Bop,Brp– Supply voltage

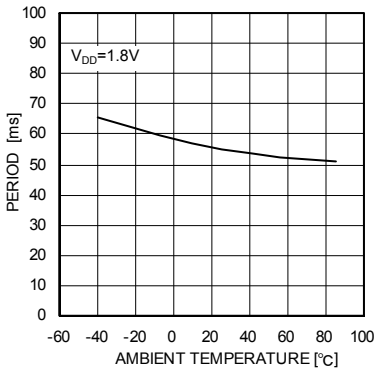


Fig.32 $T_P$ – Ambient temperature

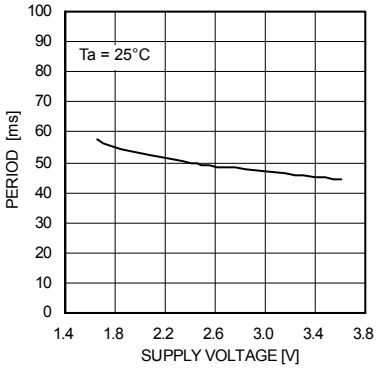


Fig.33 $T_P$– Supply voltage

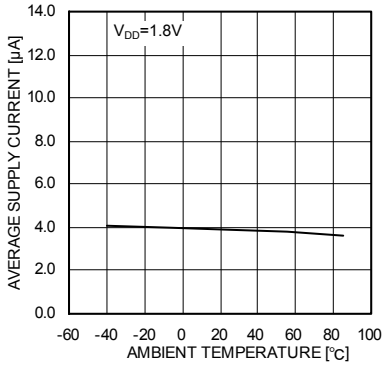


Fig.34 $I_{DD}$– Ambient temperature

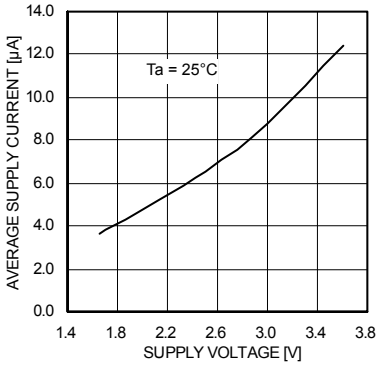


Fig.35 $I_{DD}$ – Supply voltage

## BU52053NVX ($V_{DD}$=1.65～3.6V type)

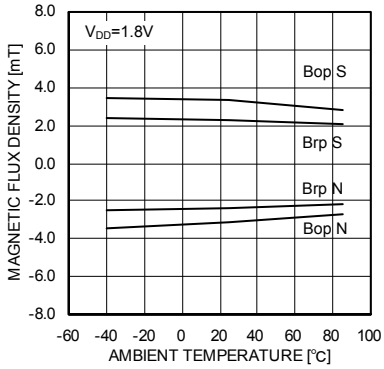


Fig.36 Bop,Brp– Ambient temperature

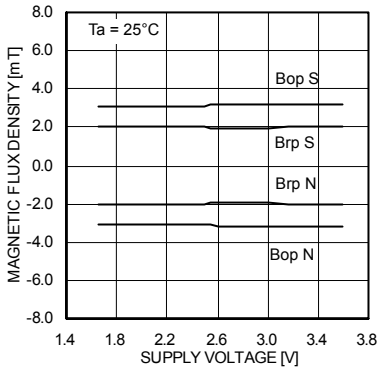


Fig.37 Bop,Brp– Supply voltage

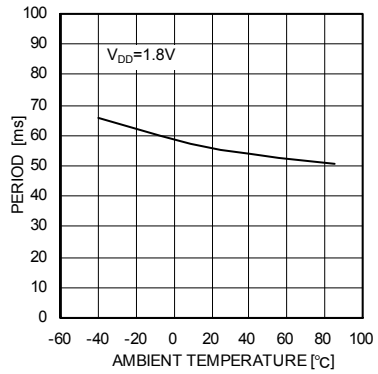


Fig.38 $T_P$ – Ambient temperature

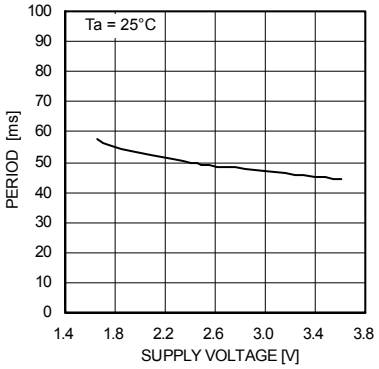


Fig.39 $T_P$– Supply voltage

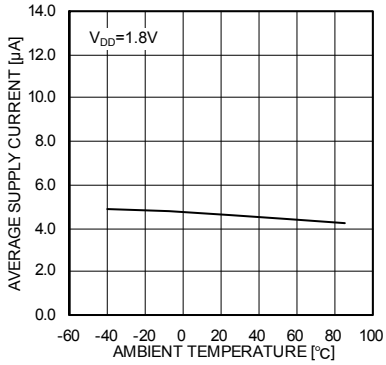


Fig.40 $I_{DD}$– Ambient temperature

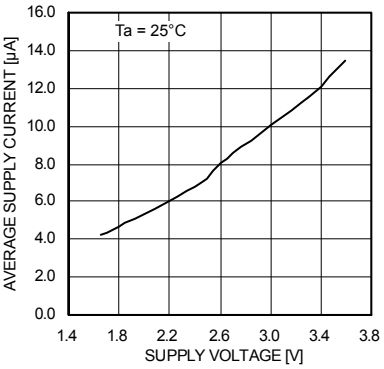


Fig.41 $I_{DD}$ – Supply voltage


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## BU52056NVX($V_{DD}$=1.65～3.6V type)

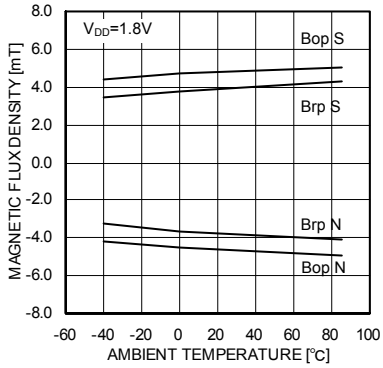


Fig.42 Bop,Brp– Ambient temperature

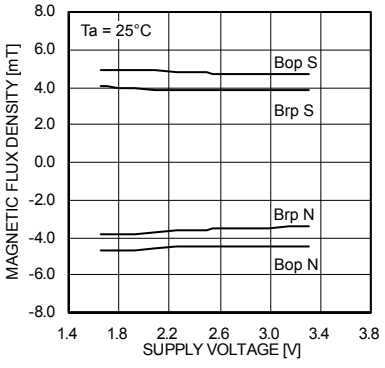


Fig.43 Bop,Brp– Supply voltage

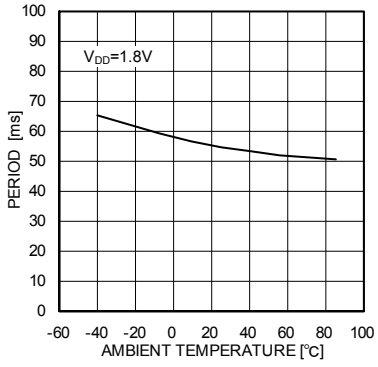


Fig.44 $T_P$ – Ambient temperature

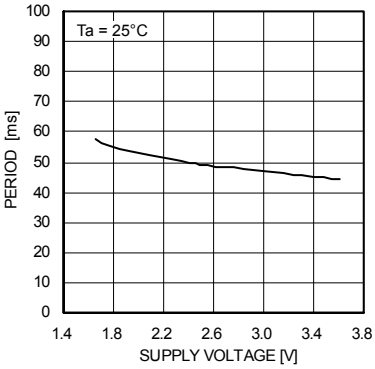


Fig.45 $T_P$– Supply voltage

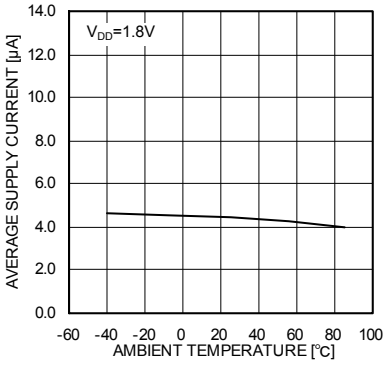


Fig.46 $I_{DD}$– Ambient temperature

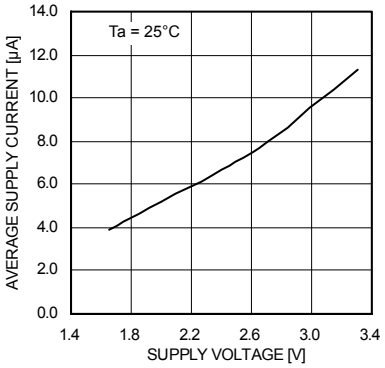


Fig.47 $I_{DD}$– Supply voltage

## BU52021HFV, BU52025G ($V_{DD}$=2.4～3.6V type)

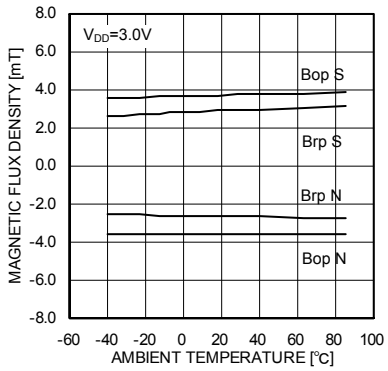


Fig.48 Bop,Brp–Ambient temperature

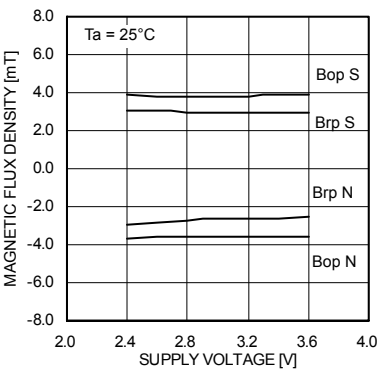


Fig.49 Bop,Brp– Supply voltage

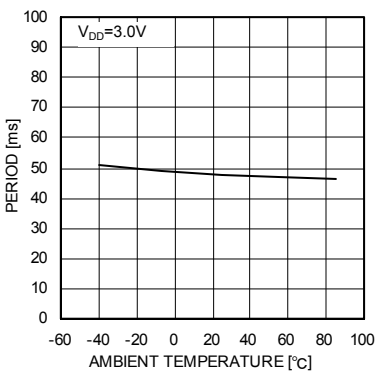


Fig.50 $T_P$ – Ambient temperature

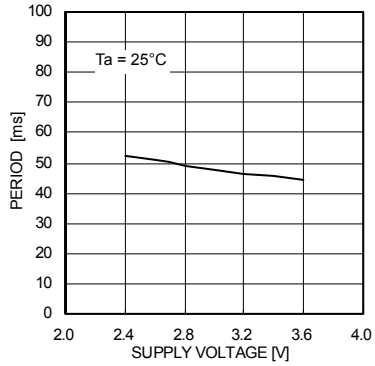


Fig.51 $T_P$ – Supply voltage

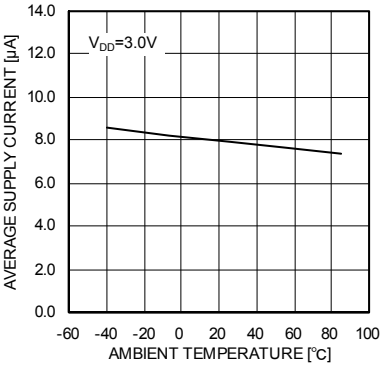


Fig.52 $I_{DD}$ – Ambient temperature

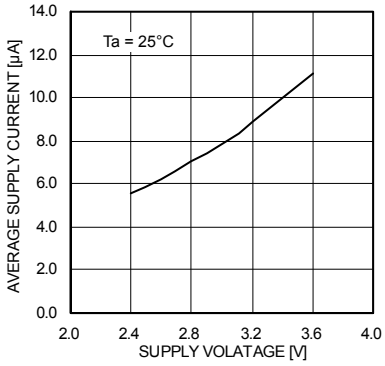


Fig.53 $I_{DD}$ – Supply voltage


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**BD7411G ($V_{DD}$=4.5～5.5V type)**

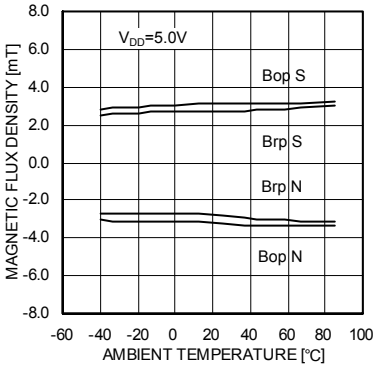


Fig.54 Bop,Brp–Ambient temperature

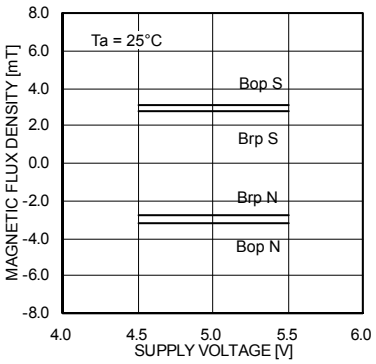


Fig.55 Bop,Brp– Supply voltage

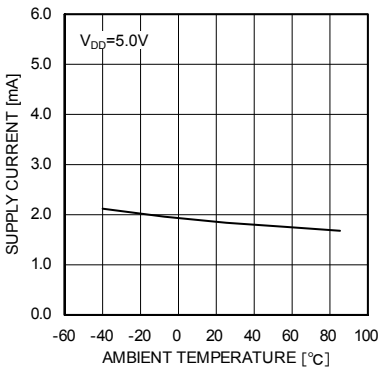


Fig.56 $I_{DD}$ – Ambient temperature

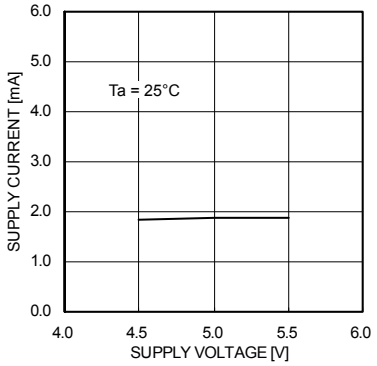


Fig.57 $I_{DD}$ – Supply voltage


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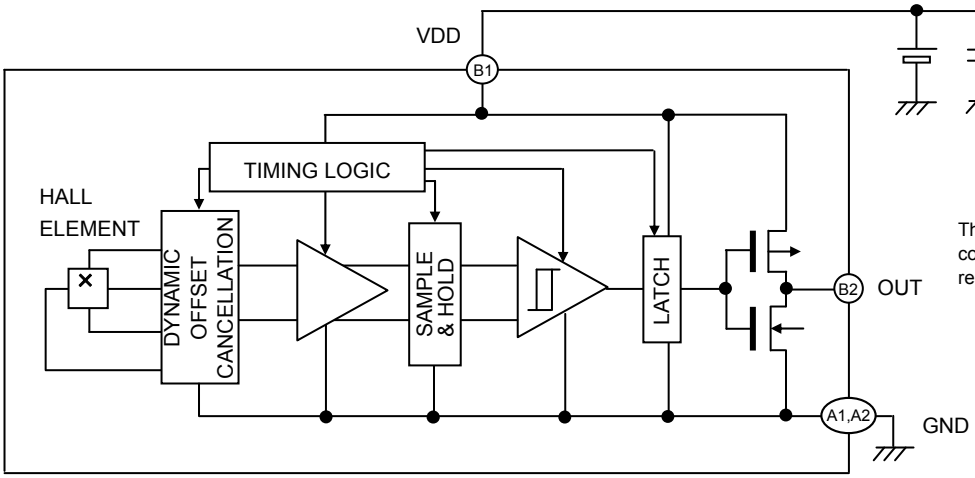
## ●Block Diagram

### BU52054GWZ, BU52055GWZ

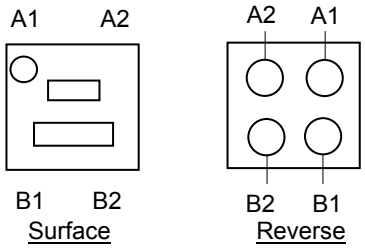



Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc.

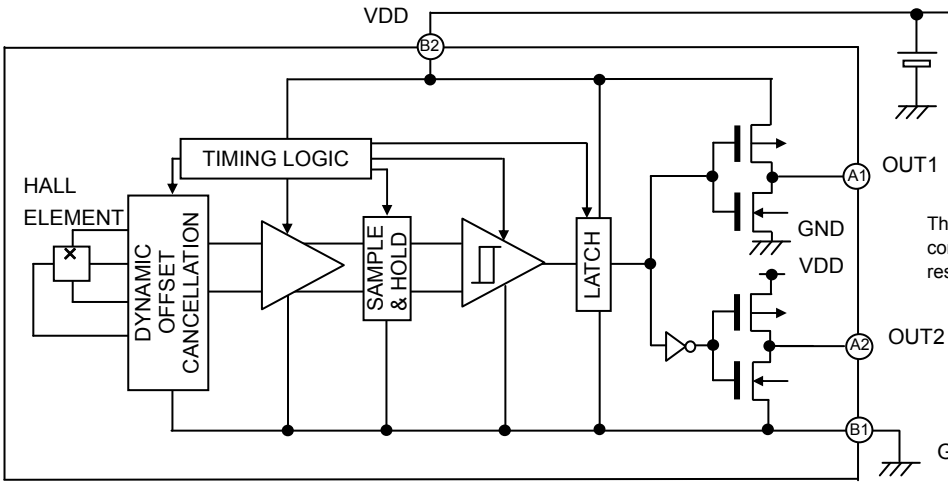
The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.

Fig.58

| PIN No. | PIN NAME | FUNCTION | COMMENT |
|---|---|---|---|
| A1 | GND | GROUND | |
| A2 | GND | GROUND | |
| B1 | VDD | POWER SUPPLY | |
| B2 | OUT | OUTPUT | |




### BU52015GUL

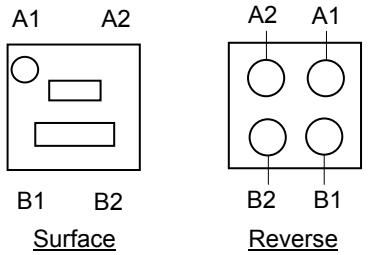



Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc.

The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.

Fig.59

| PIN No. | PIN NAME | FUNCTION | COMMENT |
|---|---|---|---|
| A1 | OUT1 | Output pin (Active Low) | |
| A2 | OUT2 | Output pin (Active High) | |
| B1 | GND | GROUND | |
| B2 | VDD | Power Supply Voltage | |





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## BU52001GUL

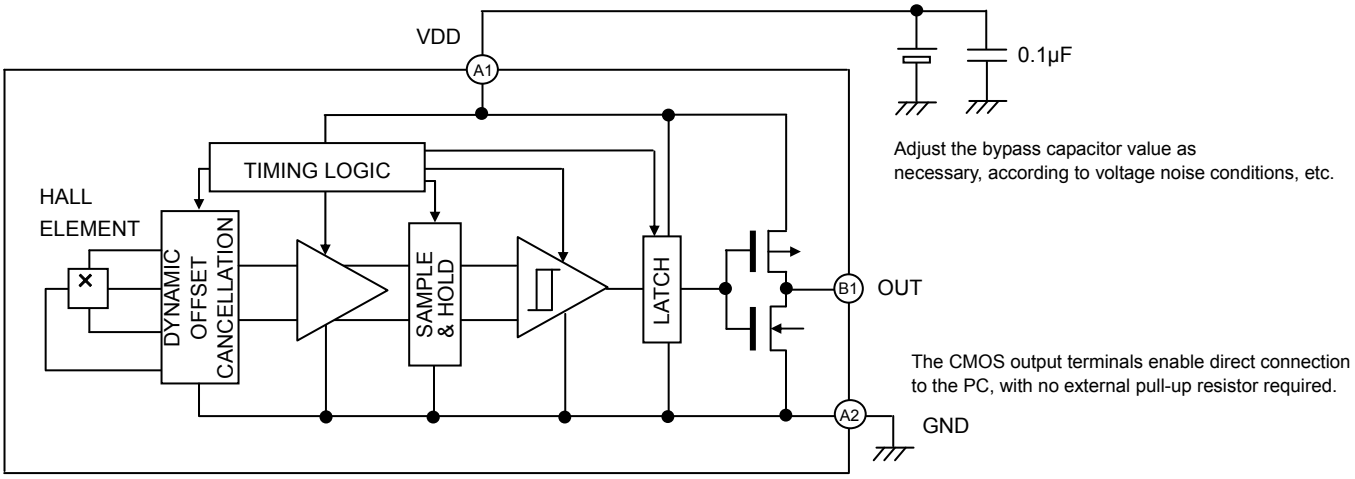
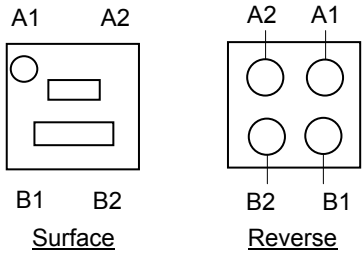



Fig.60

| PIN No. | PIN NAME | FUNCTION | COMMENT |
|---|---|---|---|
| A1 | VDD | POWER SUPPLY | |
| A2 | GND | GROUND | |
| B1 | OUT | OUTPUT | |
| B2 | N.C. | | OPEN or Short to GND. |




## BU52061NVX, BU52053NVX, BU52056NVX

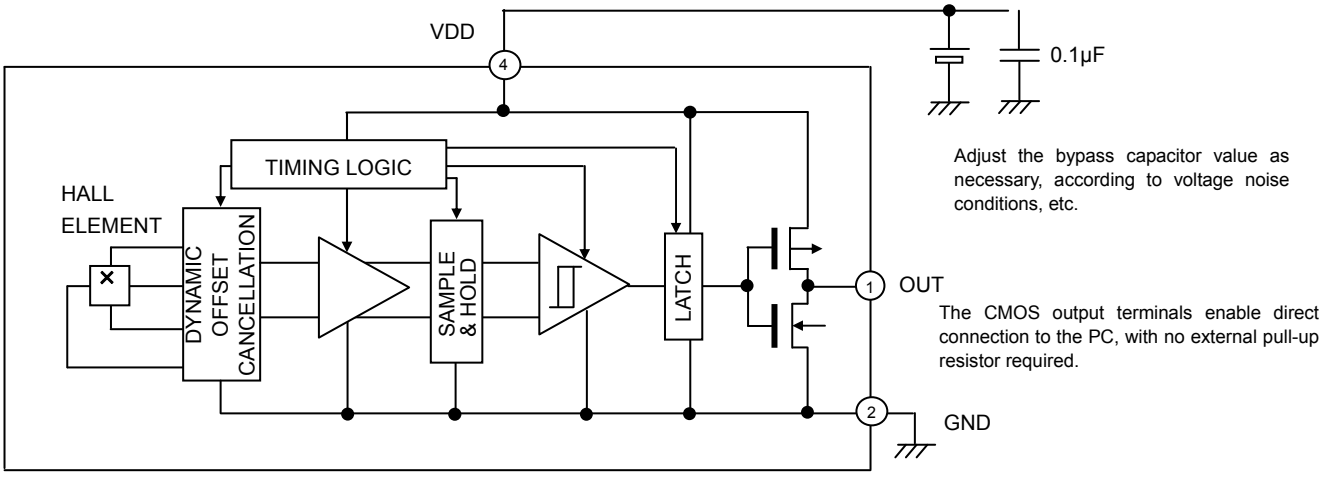
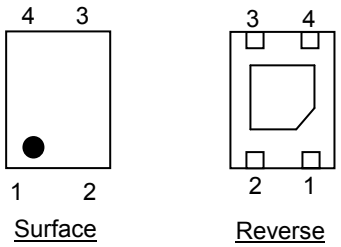



Fig.61

| PIN No. | PIN NAME | FUNCTION | COMMENT |
|---|---|---|---|
| 1 | OUT | OUTPUT | |
| 2 | GND | GROUND | |
| 3 | N.C. | | OPEN or Short to GND. |
| 4 | VDD | POWER SUPPLY | |





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## BU52011HFV, BU52021HFV

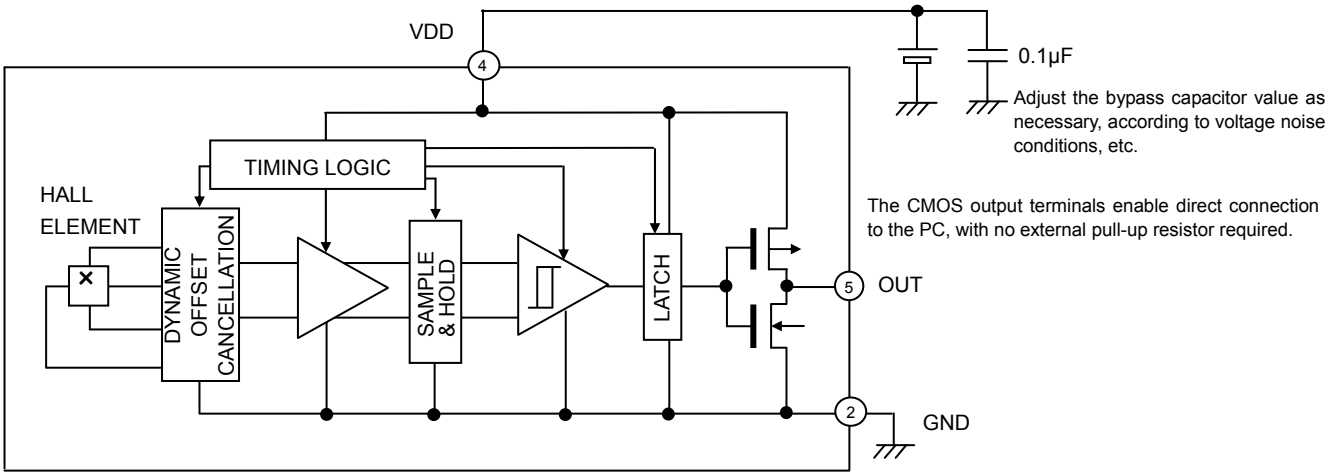
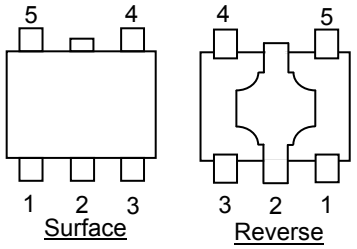



Fig.62

| PIN No. | PIN NAME | FUNCTION | COMMENT |
|---|---|---|---|
| 1 | N.C. | | OPEN or Short to GND. |
| 2 | GND | GROUND | |
| 3 | N.C. | | OPEN or Short to GND. |
| 4 | VDD | POWER SUPPLY | |
| 5 | OUT | OUTPUT | |




## BU52025G

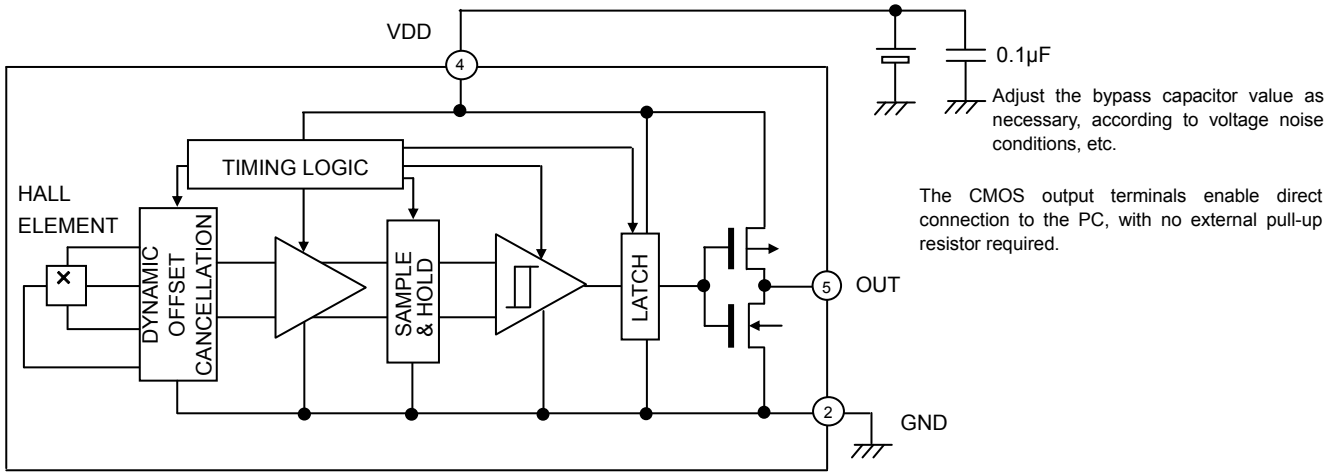
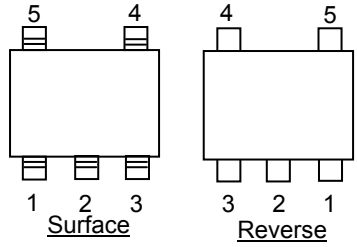



Fig.63

| PIN No. | PIN NAME | FUNCTION | COMMENT |
|---|---|---|---|
| 1 | N.C. | | OPEN or Short to GND. |
| 2 | GND | GROUND | |
| 3 | N.C. | | OPEN or Short to GND. |
| 4 | VDD | POWER SUPPLY | |
| 5 | OUT | OUTPUT | |





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**BD7411G**

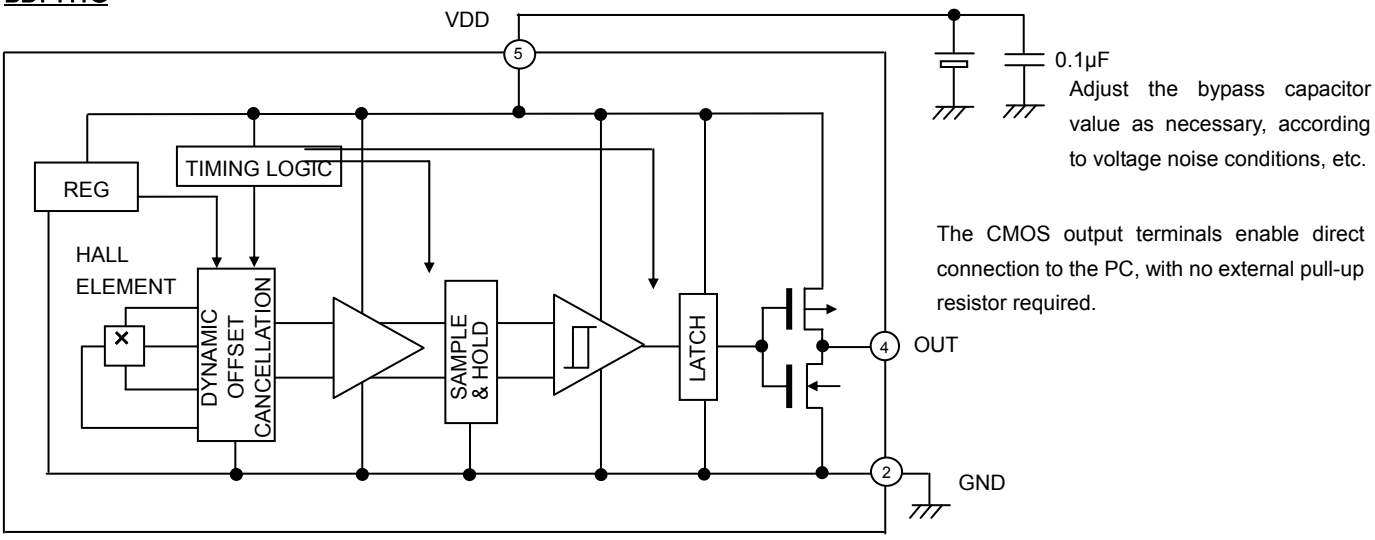
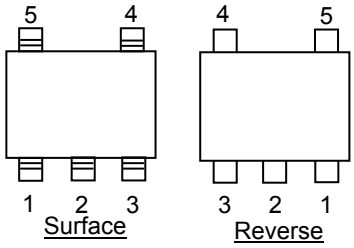



Fig.64

| PIN No. | PIN NAME | FUNCTION | COMMENT |
|---|---|---|---|
| 1 | N.C. | | OPEN or Short to GND. |
| 2 | GND | GROUND | |
| 3 | N.C. | | OPEN or Short to GND. |
| 4 | OUT | OUTPUT | |
| 5 | VDD | POWER SUPPLY | |





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## ●Description of Operations

(Micropower Operation)

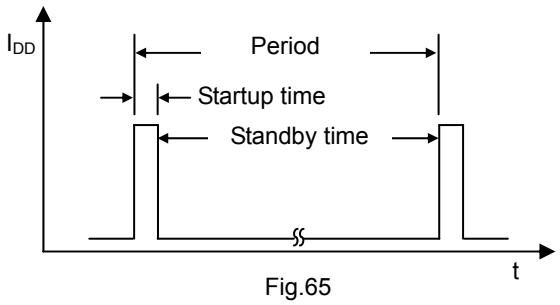


Fig.65

The bipolar detection Hall IC adopts an intermittent operation method to save energy. At startup, the Hall elements, amp, comparator and other detection circuits power ON and magnetic detection begins. During standby, the detection circuits power OFF, thereby reducing current consumption. The detection results are held while standby is active, and then output.

Reference period: 50ms (MAX100ms)
Reference startup time: 48μs

※BD7411G don't adopts an intermittent operation method.

(Offset Cancelation)

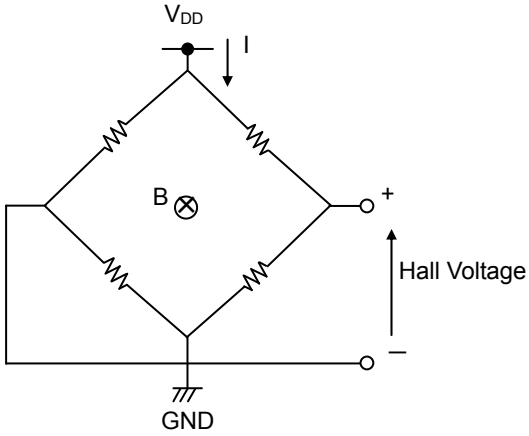


Fig.66

The Hall elements form an equivalent Wheatstone (resistor) bridge circuit. Offset voltage may be generated by a differential in this bridge resistance, or can arise from changes in resistance due to package or bonding stress. A dynamic offset cancellation circuit is employed to cancel this offset voltage.
When Hall elements are connected as shown in Fig. 66 and a magnetic field is applied perpendicular to the Hall elements, voltage is generated at the mid-point terminal of the bridge. This is known as Hall voltage.
Dynamic cancellation switches the wiring (shown in the figure) to redirect the current flow to a 90° angle from its original path, and thereby cancels the Hall voltage.
The magnetic signal (only) is maintained in the sample/hold circuit during the offset cancellation process and then released.


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(Magnetic Field Detection Mechanism)

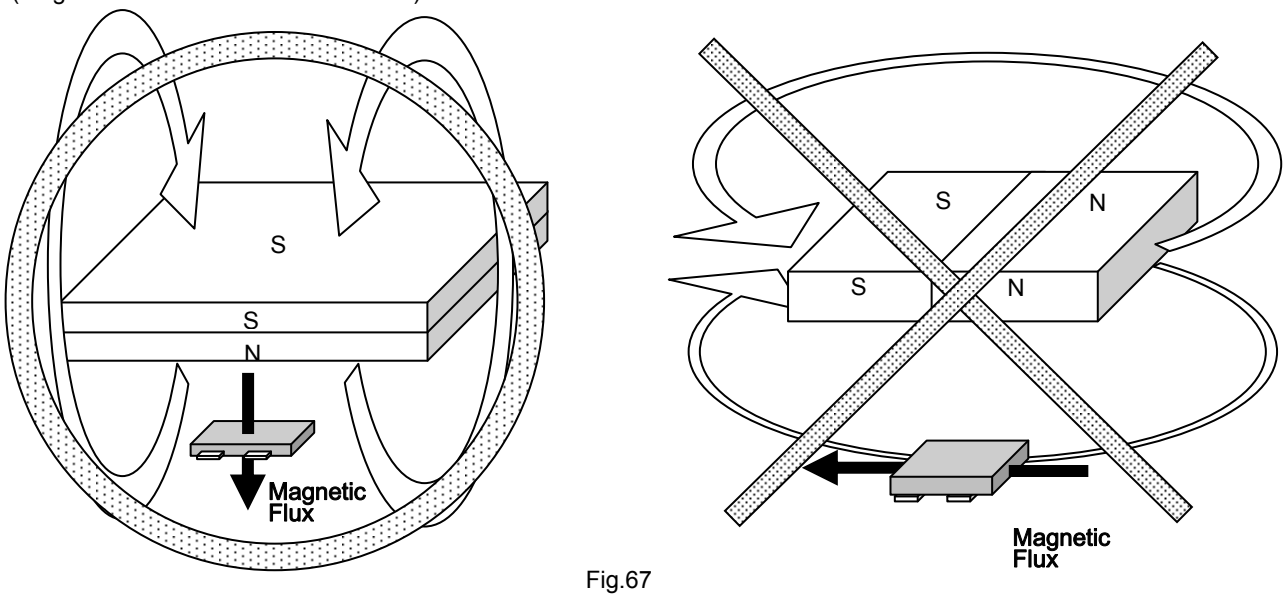


Fig.67

The Hall IC cannot detect magnetic fields that run horizontal to the package top layer.
Be certain to configure the Hall IC so that the magnetic field is perpendicular to the top layer.

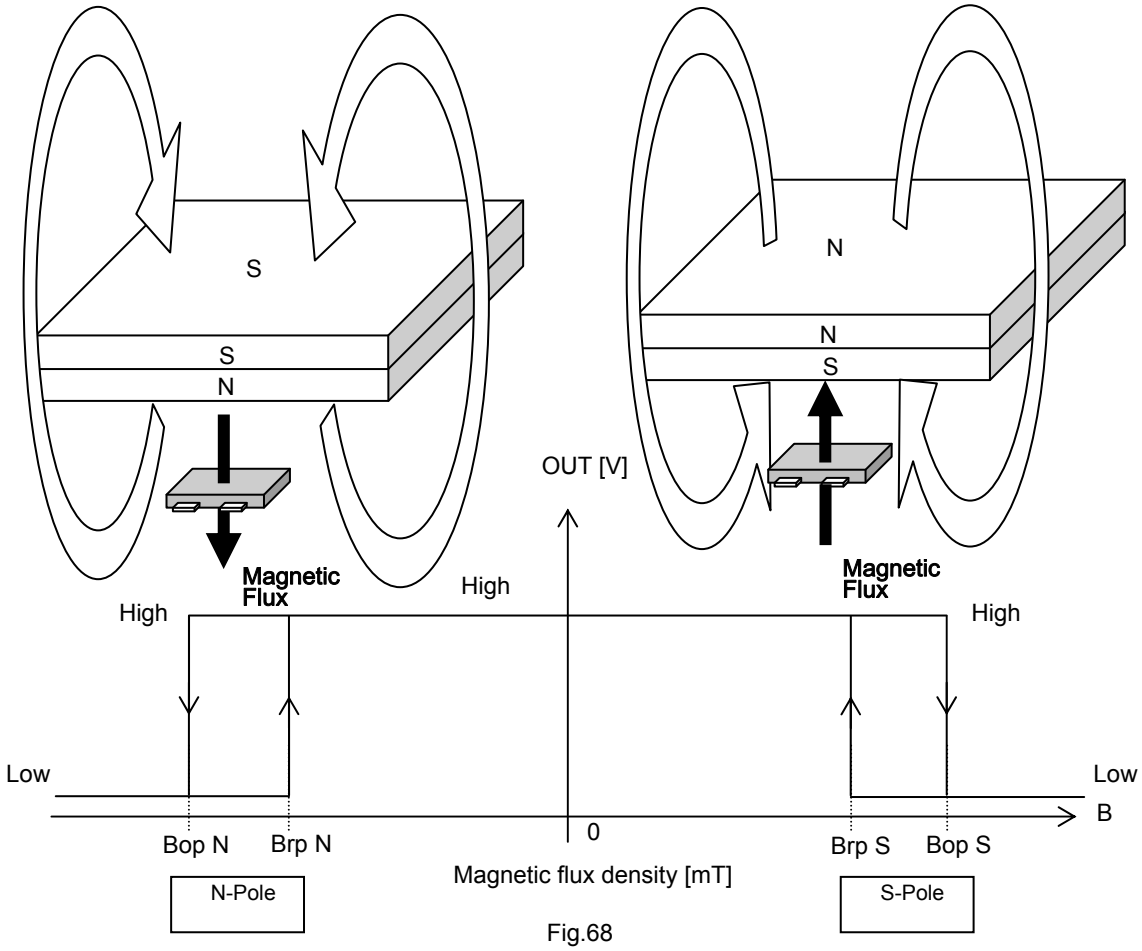


Fig.68

The bipolar detection Hall IC detects magnetic fields running perpendicular to the top surface of the package. There is an inverse relationship between magnetic flux density and the distance separating the magnet and the Hall IC: when distance increases magnetic density falls. When it drops below the operate point (Bop), output goes HIGH. When the magnet gets closer to the IC and magnetic density rises, to the operate point, the output switches LOW. In LOW output mode, the distance from the magnet to the IC increases again until the magnetic density falls to a point just below Bop, and output returns HIGH. (This point, where magnetic flux density restores HIGH output, is known as the release point, Brp.) This detection and adjustment mechanism is designed to prevent noise, oscillation and other erratic system operation.


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●Intermittent Operation at Power ON

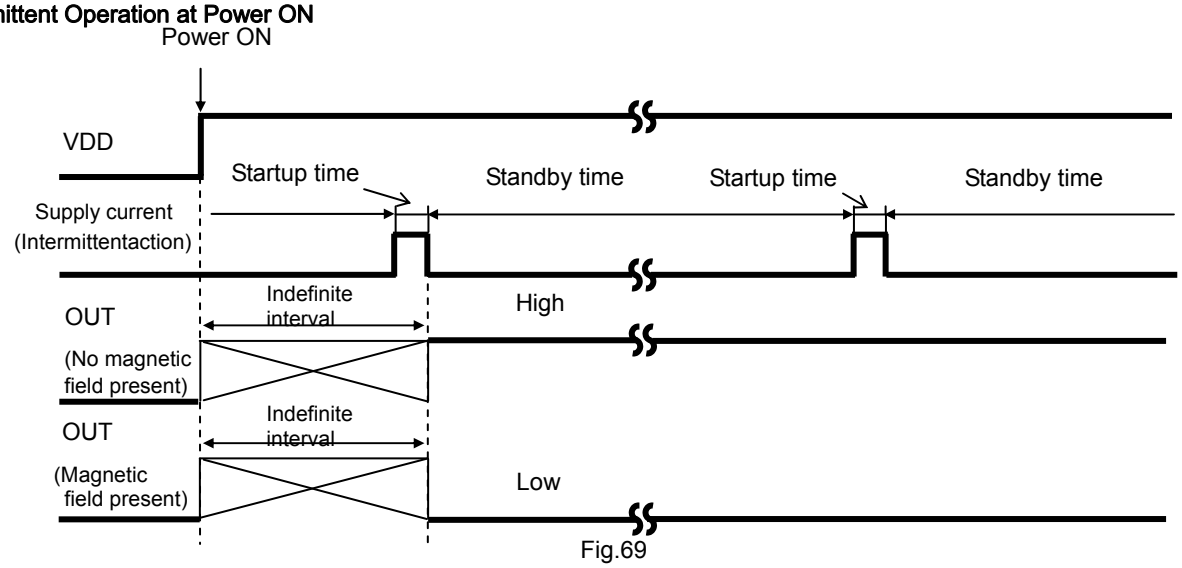


Fig.69

The bipolar detection Hall IC adopts an intermittent operation method in detecting the magnetic field during startup, as shown in Fig. 69. It outputs to the appropriate terminal based on the detection result and maintains the output condition during the standby period. The time from power ON until the end of the initial startup period is an indefinite interval, but it cannot exceed the maximum period, 100ms. To accommodate the system design, the Hall IC output read should be programmed within 100ms of power ON, but after the time allowed for the period ambient temperature and supply voltage.
※BD7411G don't adopts an intermittent operation method.

●Magnet Selection

Of the two representative varieties of permanent magnet, neodymium generally offers greater magnetic power per volume than ferrite, thereby enabling the highest degree of miniaturization, Thus, neodymium is best suited for small equipment applications. Fig. 70 shows the relation between the size (volume) of a neodymium magnet and magnetic flux density. The graph plots the correlation between the distance (L) from three versions of a 4mm X 4mm cross-section neodymium magnet (1mm, 2mm, and 3mm thick) and magnetic flux density. Fig. 71 shows Hall IC detection distance – a good guide for determining the proper size and detection distance of the magnet. Based on the BU52011HFV, BU52015GUL operating point max 5.0 mT, the minimum detection distance for the 1mm, 2mm and 3mm magnets would be 7.6mm, 9.22mm, and 10.4mm, respectively. To increase the magnet's detection distance, either increase its thickness or sectional area.

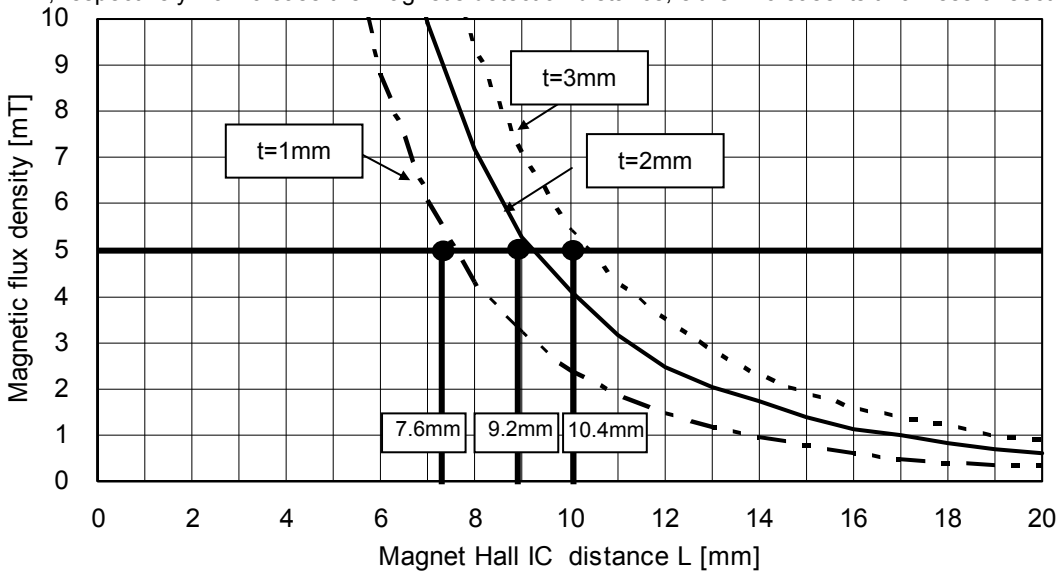


Fig.70

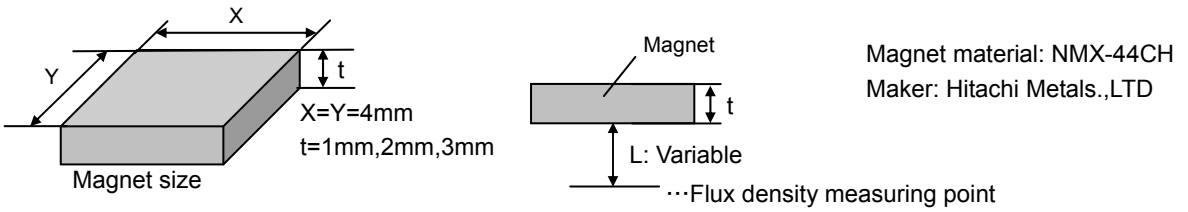


Fig.71 Magnet Dimensions and Flux Density Measuring Point


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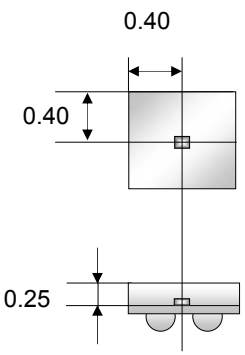
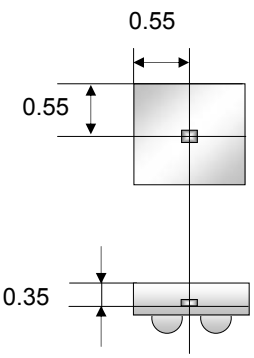
●Position of the Hall Effect IC(Reference)

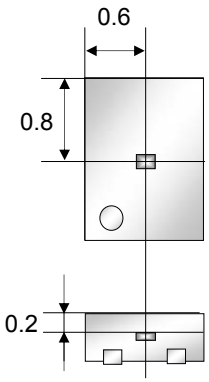
UCSP35L1



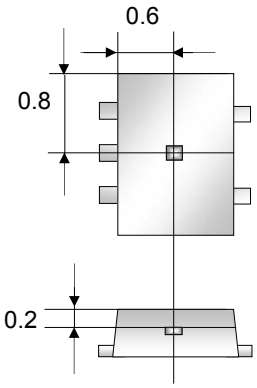

VCSP50L1



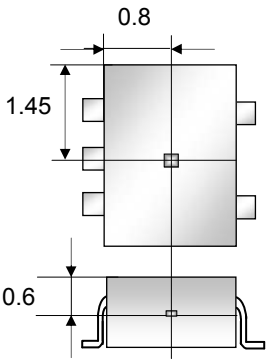

SSON004X1216




HVSOF5



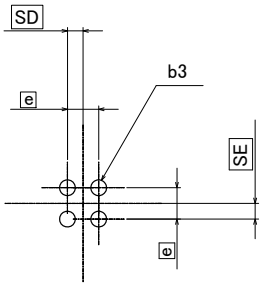

SSOP5




(UNIT:mm)

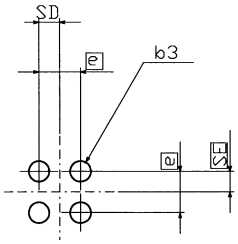
●Footprint dimensions (Optimize footprint dimensions to the board design and soldering condition)

UCSP35L1



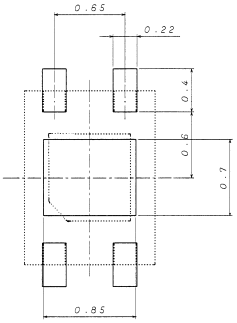

| Symbol | Reference Value |
|---|---|
| e | 0.40 |
| b3 | Φ0.20 |
| SD | 0.20 |
| SE | 0.20 |

VCSP50L1



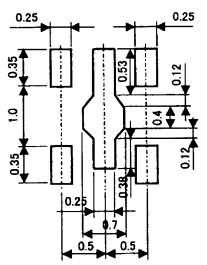

| Symbol | Reference Value |
|---|---|
| e | 0.50 |
| b3 | 0.25 |
| SD | 0.25 |
| SE | 0.25 |

SSON004X1216

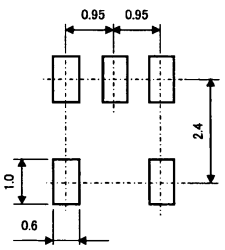



Please avoid having potential overstress from PCB material, strength, mounting positions.
If you had any further questions or concerns, please contact your Rohm sales and affiliate.

HVSOF5




SSOP5




(UNIT:mm)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●Terminal Equivalent Circuit Diagram

OUT , OUT1, OUT2

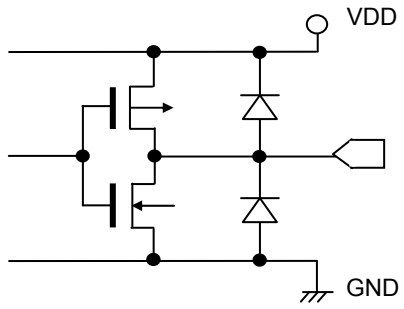


Fig.72

Because they are configured for CMOS (inverter) output, the output pins require no external resistance and allow direct connection to the PC. This, in turn, enables reduction of the current that would otherwise flow to the external resistor during magnetic field detection, and supports overall low current (micropower) operation.


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## ●Notes for use

1) Absolute maximum ratings
Exceeding the absolute maximum ratings for supply voltage, operating conditions, etc. may result in damage to or destruction of the IC. Because the source (short mode or open mode) cannot be identified if the device is damaged in this way, it is important to take physical safety measures such as fusing when implementing any special mode that operates in excess of absolute rating limits.

2) GND voltage
Make sure that the GND terminal potential is maintained at the minimum in any operating state, and is always kept lower than the potential of all other pins.

3) Thermal design
Use a thermal design that allows for sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

4) Pin shorts and mounting errors
Use caution when positioning the IC for mounting on printed circuit boards. Mounting errors, such as improper positioning or orientation, may damage or destroy the device. The IC may also be damaged or destroyed if output pins are shorted together, or if shorts occur between the output pin and supply pin or GND.

5) Positioning components in proximity to the Hall IC and magnet
Positioning magnetic components in close proximity to the Hall IC or magnet may alter the magnetic field, and therefore the magnetic detection operation. Thus, placing magnetic components near the Hall IC and magnet should be avoided in the design if possible. However, where there is no alternative to employing such a design, be sure to thoroughly test and evaluate performance with the magnetic component(s) in place to verify normal operation before implementing the design.

6) Slide-by position sensing
Fig.73 depicts the slide-by configuration employed for position sensing. Note that when the gap (d) between the magnet and the Hall IC is narrowed, the reverse magnetic field generated by the magnet can cause the IC to malfunction. As seen in Fig.74, the magnetic field runs in opposite directions at Point A and Point B. Since the bipolar detection Hall IC can detect the S-pole at Point A and the N-pole at Point B, it can wind up switching output ON as the magnet slides by in the process of position detection. Fig. 75 plots magnetic flux density during the magnet slide-by. Although a reverse magnetic field was generated in the process, the magnetic flux density decreased compared with the center of the magnet. This demonstrates that slightly widening the gap (d) between the magnet and Hall IC reduces the reverse magnetic field and prevents malfunctions.

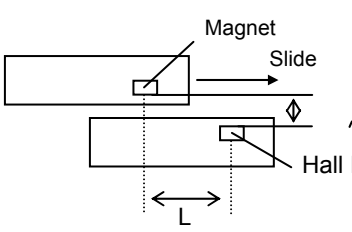

Fig.73

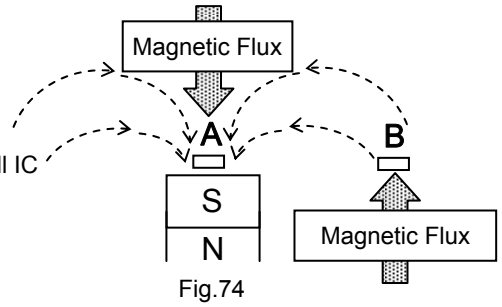

Fig.74

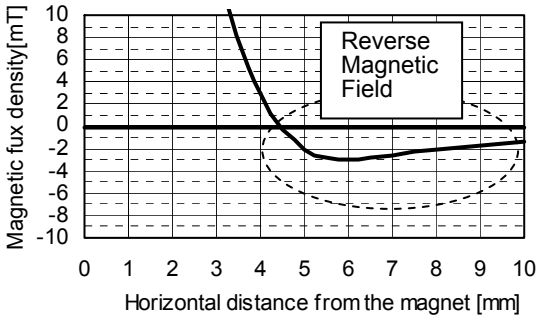

Fig.75

7) Operation in strong electromagnetic fields
Exercise extreme caution about using the device in the presence of a strong electromagnetic field, as such use may cause the IC to malfunction.

8) Common impedance
Make sure that the power supply and GND wiring limits common impedance to the extent possible by, for example, employing short, thick supply and ground lines. Also, take measures to minimize ripple such as using an inductor or capacitor.

9) GND wiring pattern
When both a small-signal GND and high-current GND are provided, single-point grounding at the reference point of the set PCB is recommended, in order to separate the small-signal and high-current patterns, and to ensure that voltage changes due to the wiring resistance and high current do not cause any voltage fluctuation in the small-signal GND. In the same way, care must also be taken to avoid wiring pattern fluctuations in the GND wiring pattern of external components.

10) Exposure to strong light
Exposure to halogen lamps, UV and other strong light sources may cause the IC to malfunction. If the IC is subject to such exposure, provide a shield or take other measures to protect it from the light. In testing, exposure to white LED and fluorescent light sources was shown to have no significant effect on the IC.

11) Power source design
Since the IC performs intermittent operation, it has peak current when it's ON. Please taking that into account and under examine adequate evaluations when designing the power source.


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●**Ordering part number**

| B | U | 5 | 2 | 0 | 0 | 1 | G | U | L | - | E | 2 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|

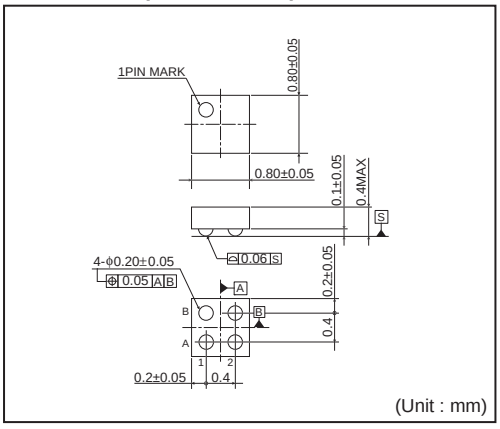
Part No.
BU, BD

Part No.
52054, 52055, 52015
52001, 52061, 52053
52056, 52011, 52021
52025, 7411

Package
GWZ : UCSP35L1
GUL : VSCP50L1
NVX : SSON004X1216
HFV : HVSOF5
G : SSOP5

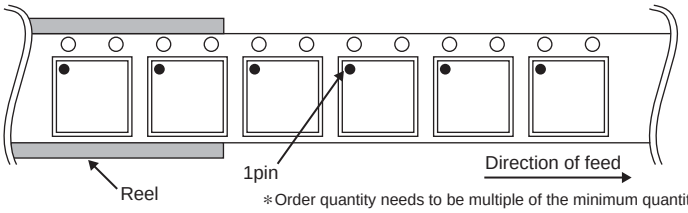
Packaging and forming specification
E2: Embossed tape and reel
(UCSP35L1, VSCP50L1)
TR: Embossed tape and reel
(SSON004X1216,HVSOF5, SSOP5)

**UCSP35L1(BU52054GWZ)**



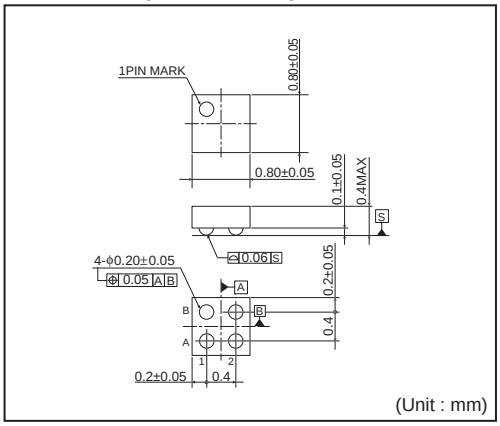

<Tape and Reel information>

| Tape | Embossed carrier tape |
|---|---|
| Quantity | 3000pcs |
| Direction of feed | E2 ( The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand ) |



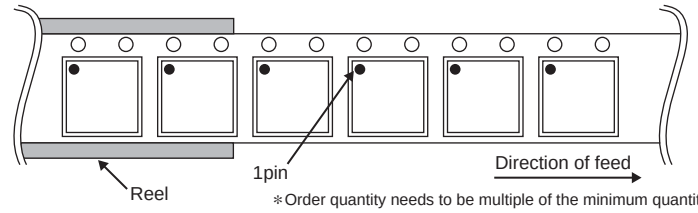

∗Order quantity needs to be multiple of the minimum quantity.

**UCSP35L1(BU52055GWZ)**




<Tape and Reel information>

| Tape | Embossed carrier tape |
|---|---|
| Quantity | 3000pcs |
| Direction of feed | E2 ( The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand ) |




∗Order quantity needs to be multiple of the minimum quantity.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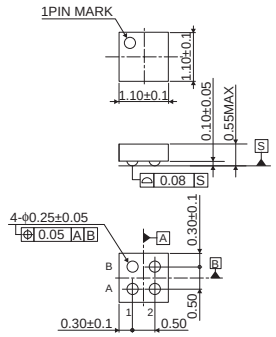
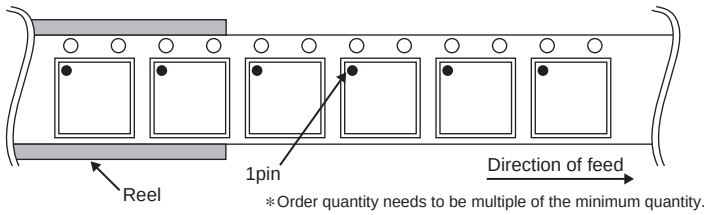
### VCSP50L1(BU52015GUL)




(Unit : mm)

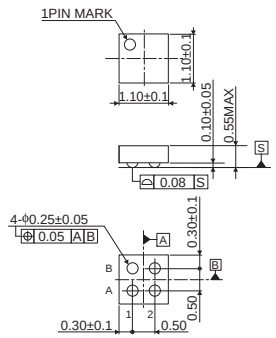
<Tape and Reel information>

| | |
|---|---|
| Tape | Embossed carrier tape |
| Quantity | 3000pcs |
| Direction of feed | E2<br>( The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand ) |




∗Order quantity needs to be multiple of the minimum quantity.

### VCSP50L1(BU52001GUL)




(Unit : mm)

<Tape and Reel information>

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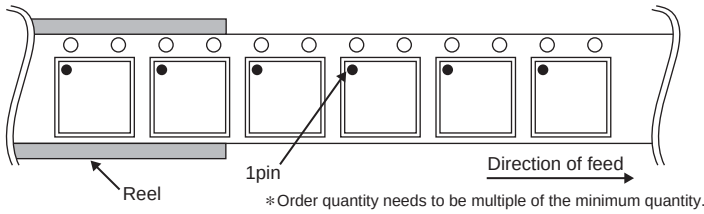
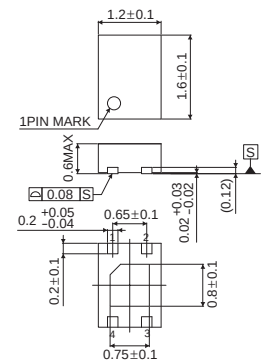
|---|---|
| Tape | Embossed carrier tape |
| Quantity | 3000pcs |
| Direction of feed | E2<br>( The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand ) |




∗Order quantity needs to be multiple of the minimum quantity.

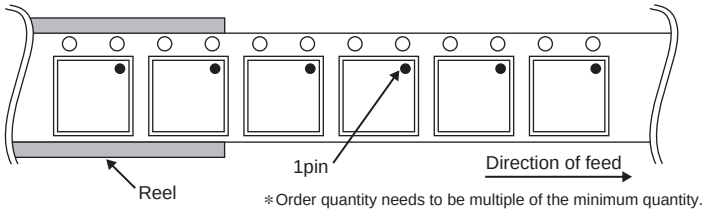
### SSON004X1216




(Unit : mm)

<Tape and Reel information>

| | |
|---|---|
| Tape | Embossed carrier tape |
| Quantity | 5000pcs |
| Direction of feed | TR<br>( The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand ) |




∗Order quantity needs to be multiple of the minimum quantity.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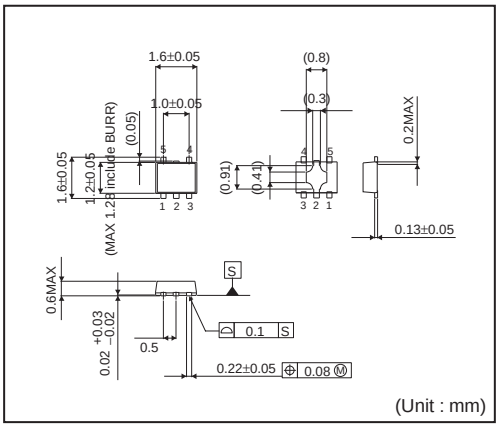
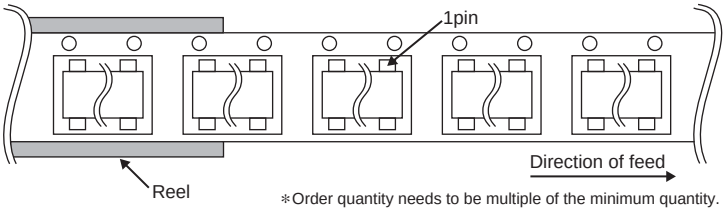
## HVSOF5



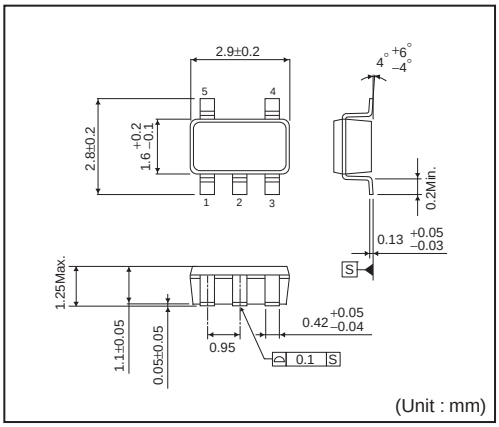

<Tape and Reel information>

| | |
|---|---|
| Tape | Embossed carrier tape |
| Quantity | 3000pcs |
| Direction of feed | TR<br>( The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand ) |




∗Order quantity needs to be multiple of the minimum quantity.

## SSOP5




<Tape and Reel information>

| | |
|---|---|
| Tape | Embossed carrier tape |
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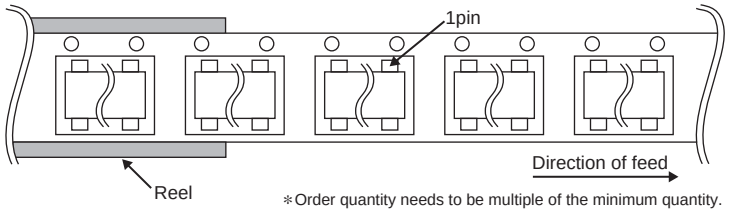
| Direction of feed | TR<br>( The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand ) |




∗Order quantity needs to be multiple of the minimum quantity.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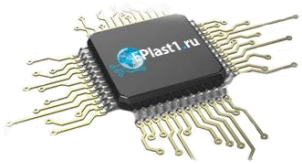
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.

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**Телефон:** 8 (812) 309 58 32 (многоканальный)
**Факс:** 8 (812) 320-02-42
**Электронная почта:** org@eplast1.ru
**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.